










	<h2>SIHP30N60E-GE3</h2>
	<p>Hersteller-Teilenummer: SIHP30N60E-GE3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 29A TO220AB</p> <p>Datenblätter:  SIHP30N60E-GE3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 7169 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SIHP30N60E-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 600V 29A TO220AB
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	7169 pcs Stock
Serie	E
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Through Hole
Verpackung / Gehäuse	TO-220-3
Verlustleistung (max)	250W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	600V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	29A (Tc)
Rds On (Max) @ Id, Vgs	125 mOhm @ 15A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	130nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	2600pF @ 100V
Vgs (Max)	±30V
Verpackung	Original-Reel®



















































SIHP30N60E-GE3 ist neu im Original, Suche SIHP30N60E-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHP30N60E-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SIHP30N60E-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SIHP30N60E-E3 Vishay / Siliconix MOSFET N-CH 600V 29A TO220AB</p>	 <p>SIHP33N60EF-GE3 Vishay / Siliconix MOSFET N-CH 600V 33A TO-220-3</p>	 <p>SIHP33N60EF-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 33A TO-220-3</p>	 <p>SIHP30N60E-GE3 Vishay / Spectrol MOSFET N-CH 600V 29A TO220AB</p>
 <p>SIHP33N60E-GE3 Vishay / Siliconix MOSFET N-CH 600V 33A TO-220AB</p>	 <p>SIHP30N60E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 29A TO220AB</p>	 <p>SIHP33N60E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 33A TO-220AB</p>	 <p>SIHP35N60E Vishay Precision Group SIHP35N60E vishay</p>

heiße Teile

Mehr

 SIHFSL11N50A	 SIHG16N50C-E3	 SIHG16N50C-E3	 SIHG17N60D	 SIHG20N50C
 SIHG22N60S-E3	 SIHG30N60E	 SIHG33N60E	 SIHG47N60E-E3	 SIHG47N60E-E3
 SIHG47N60E-GE3	 SIHG47N60E-GE3	 SIHG47N60S-E3	 SIHG70N60EFEF-GE3	 SIHG73N60E-GE3
 SIHG73N60E-GE3	 SIHP10N40D	 SIHP12N50C-E3	 SIHP12N50C-E3	 SIHP12N60E-E3
 SIHP12N60E-E3	 SIHP12N60E-GE3	 SIHP12N60E-GE3	 SIHP12N65E	 SIHP14N50D
 SIHP15N60E-E3	 SIHP15N60E-E3	 SIHP15N65E	 SIHP16N50C-E3	 SIHP16N50C-E3
 SIHP17N60D-E3	 SIHP17N60D-E3	 SIHP18N50C-E3	 SIHP18N50C-E3	 SIHP22N60S-E3
 SIHP30N60E-E3	 SIHP30N60E-E3	 SIHP30N60E-GE3	 SIHP30N60E-GE3	 SIHP33N60E-GE3
 SIHP33N60E-GE3	 SIHP5N50D-E3	 SIHP5N50D-E3	 SIHP6N40D	 SIHP8N50D-E3
 SIHP8N50D-E3	 SIHU3N50D-E3	 SIHU3N50D-E3	 SIHW30N60E-GE3	 SIHW30N60E-GE3

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